

## characteristics:

It is used to drive IGBT, MOS pipe and transmit high-frequency signal isolation.

## Technical indicators:

Installation method: PCB

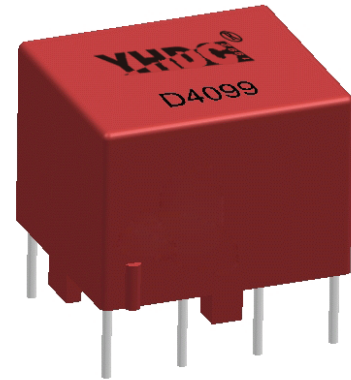
Flame resistance: UL94-V0

Operating temperature:  $-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$

Storage temperature:  $-40^{\circ}\text{C} \sim +90^{\circ}\text{C}$

Frequency range: 30KHz $\sim$ 200KHz

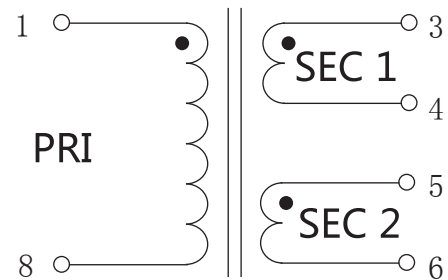
Dielectric strength: 3.1KV 50Hz 1min



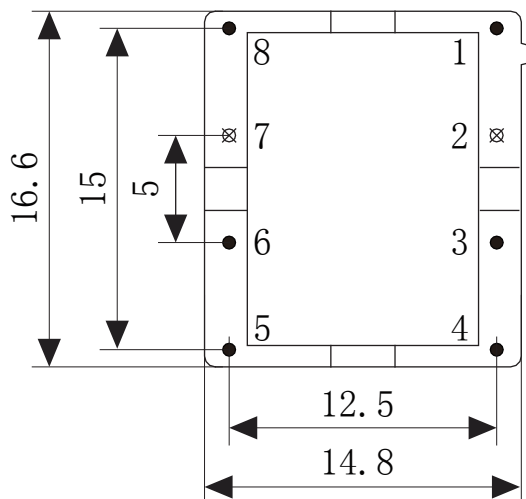
## Electrical parameters:

Vout microsecond integral	150	$\mu\text{Vs}$
Pulse width (D=1:2)	7.5	$\mu\text{s}$
Ratio	2:1:1	
Input amplitude	20	V
Output amplitude	8.8	V
Load impedance	100	$\Omega$
Leading edge time	$\leq 1$	$\mu\text{s}$
Main circuit operating voltage	380	V
Weight		g

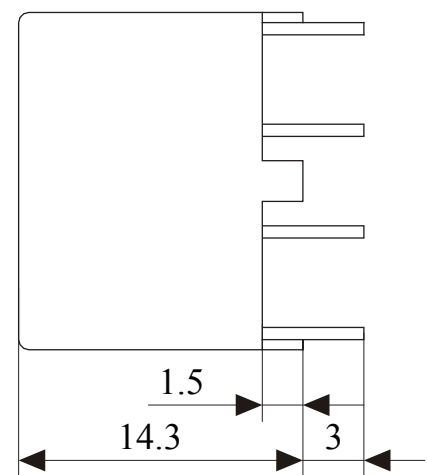
## Connection diagram:



## Dimensions (in mm) :



Bottom View



Side View